

MPS3703



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PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Thermal Characteristics TA = 25°C unless otherwise noted				
Symbol	Characteristic	Max	Units	
		MPS3703	-	
PD	Total Device Dissipation Derate above 25°C	625 5.0	m₩ mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
R _{θJA}	Thermal Resistance, Junction to Ambient	200	°C/W	

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PNP General Purpose Amplifier (continued)

Electrical Characteristics TA = 25°C unless otherwise noted					
Symbol	Parameter	Test Conditions	Min	Max	Units

OFF CHARACTERISTICS

V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{mA}, I_{\rm B} = 0$	30		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, I_{\rm E} = 0$	50		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 100 \ \mu A, I_{C} = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20 V, I_E = 0$		100	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		100	nA

ON CHARACTERISTICS*

h _{FE}	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 50 \text{ mA}$	30	150	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA		0.25	V
V _{BE(on)}	Base-Emitter On Voltage	$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 5.0 V	0.6	1.0	V

SMALL SIGNAL CHARACTERISTICS

C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1.0 MHz		12	pF
f _T	Current Gain - Bandwidth Product	$I_{C} = 50 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 20 MHz	100		MHz

*Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%



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